# PBSS5240X 40 V, 2 A PNP low VCEsat (BISS) transistor 19 October 2012

Product data sheet

### 1. Product profile

#### 1.1 General description

PNP low V<sub>CEsat</sub> Breakthrough In Small Signal (BISS) transistor in a medium power and flat lead SOT89 Surface-Mounted Device (SMD) plastic package. NPN complement: PBSS4240X.

#### **1.2 Features and benefits**

- Low collector-emitter saturation voltage V<sub>CEsat</sub>
- High collector current capability I<sub>C</sub> and I<sub>CM</sub>
- High efficiency due to less heat generation

#### **1.3 Applications**

- DC-to-DC conversion
- Supply line switching
- Battery charger
- LCD backlighting
- Driver in low supply voltage applications (e.g. lamps and LEDs)
- Inductive load driver (e.g. relays, buzzers and motors)

### 1.4 Quick reference data

Table 1. Qui	Table 1. Quick reference data						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	-40	V
I <sub>C</sub>	collector current			-	-	-2	Α
I <sub>CM</sub>	peak collector current			-	-	-3	А
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_{C}$ = -1 A; $I_{B}$ = -100 mA; pulsed; $t_{p}$ ≤ 300 μs; δ ≤ 0.02 ; $T_{amb}$ = 25 °C		-	-	310	mΩ
I <sub>CRM</sub>	repetitive peak collector current	$t_p \leq 20$ ms; $\delta \leq 0.33$ ; pulsed		-	-	-2.5	A

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### 2. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter		С
2	С	collector		в
3	В	base		E sym132
			SOT89	-,

### 3. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PBSS5240X	SOT89	plastic surface-mounted package; die pad for good heat transfer; 3 leads	SOT89			

### 4. Marking

Table 4. Marking codes			
Type number	Marking code		
PBSS5240X	S48		

# 5. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-40	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-40	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-5	V
I <sub>C</sub>	collector current			-	-2	А
I <sub>CRM</sub>	repetitive peak collector current	$\delta \leq 0.33$ ; $t_p \leq 20$ ms; pulsed		-	-2.5	А
I <sub>CM</sub>	peak collector current			-	-3	А
I <sub>B</sub>	base current			-	-300	mA
I <sub>BM</sub>	peak base current			-	-1	А
P <sub>tot</sub>	total power dissipation		[1]	-	0.5	W
			[2]	-	0.95	W

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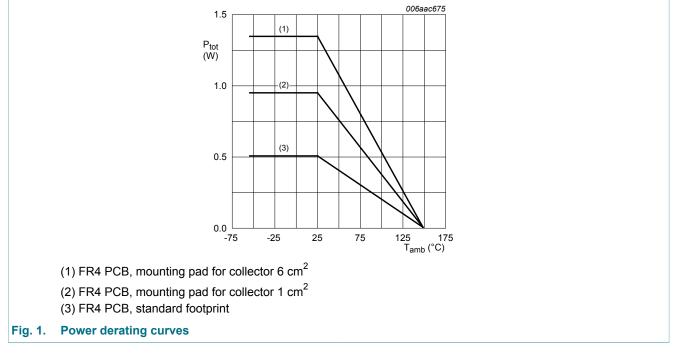
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Symbol	Parameter	Conditions		Min	Max	Unit
			[3]	-	1.35	W
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.



### 6. Thermal characteristics

Table 6. T	hermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance	in free air	[1]	-	-	250	K/W
	from junction to ambient		[2]	-	-	132	K/W
	ampient		[3]	-	-	93	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	16	K/W

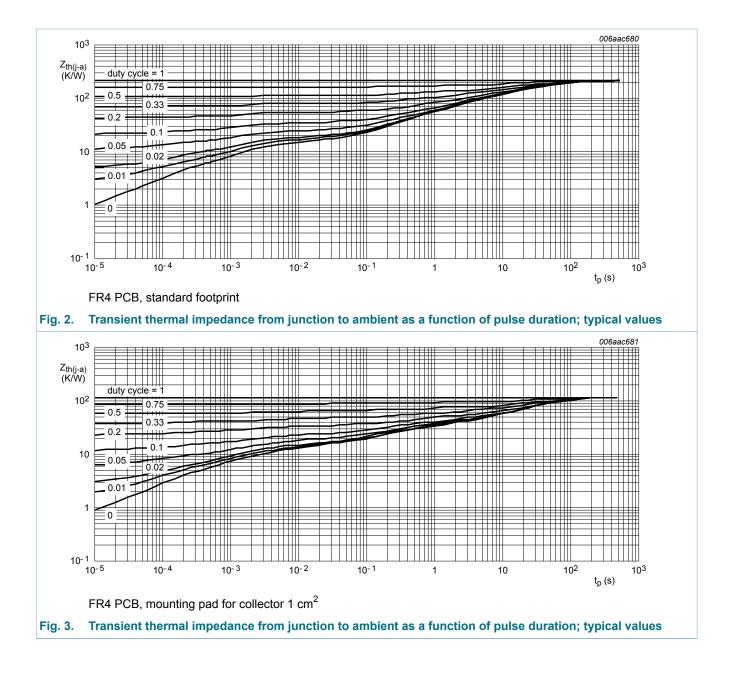
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.



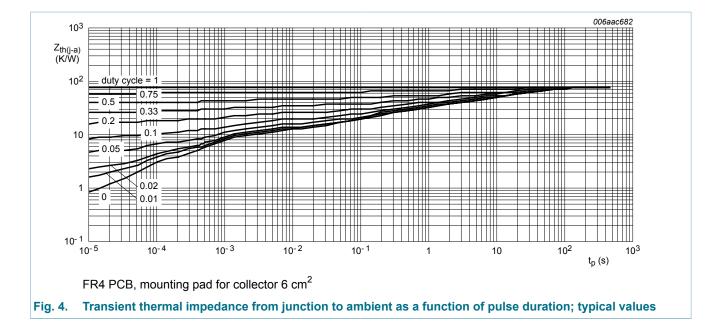
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### 7. Characteristics

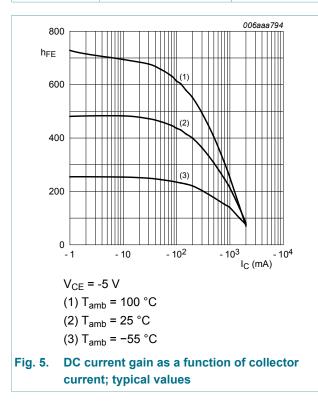
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	$V_{CB}$ = -40 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	-100	nA
	current	V <sub>CB</sub> = -40 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C	-	-	-50	μA
I <sub>CEO</sub>	collector-emitter cut-off current	$V_{CE}$ = -30 V; I <sub>B</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	-100	nA
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = -5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	-100	nA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -5 V; I <sub>C</sub> = -1 mA; T <sub>amb</sub> = 25 °C	300	-	-	
		$V_{CE}$ = -5 V; I <sub>C</sub> = -500 mA; T <sub>amb</sub> = 25 °C	215	-	-	
		V <sub>CE</sub> = -5 V; I <sub>C</sub> = -1 A; T <sub>amb</sub> = 25 °C	145	-	-	
		$V_{CE}$ = -5 V; I <sub>C</sub> = -2 A; pulsed; t <sub>p</sub> ≤ 300 µs; $\delta$ ≤ 0.02 ; T <sub>amb</sub> = 25 °C	55	-	-	
V <sub>CEsat</sub>	collector-emitter	$I_{C}$ = -100 mA; $I_{B}$ = -5 mA; $T_{amb}$ = 25 °C	-	-	-140	mV
	saturation voltage	I <sub>C</sub> = -500 mA; I <sub>B</sub> = -50 mA; T <sub>amb</sub> = 25 °C	-	-	-170	mV
		$I_{C}$ = -1 A; $I_{B}$ = -100 mA; pulsed; $t_{p} \le 300 \ \mu$ s; δ ≤ 0.02 ; $T_{amb}$ = 25 °C	-	-	-310	mV
		$I_{C}$ = -2 A; $I_{B}$ = -200 mA; pulsed; $t_{p} \le 300 \ \mu$ s; δ ≤ 0.02 ; $T_{amb}$ = 25 °C	-	-	-630	mV
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_{C}$ = -1 A; $I_{B}$ = -100 mA; pulsed; $t_{p} \le 300 \ \mu$ s; δ ≤ 0.02 ; $T_{amb}$ = 25 °C	-	-	310	mΩ

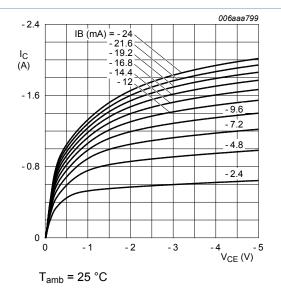
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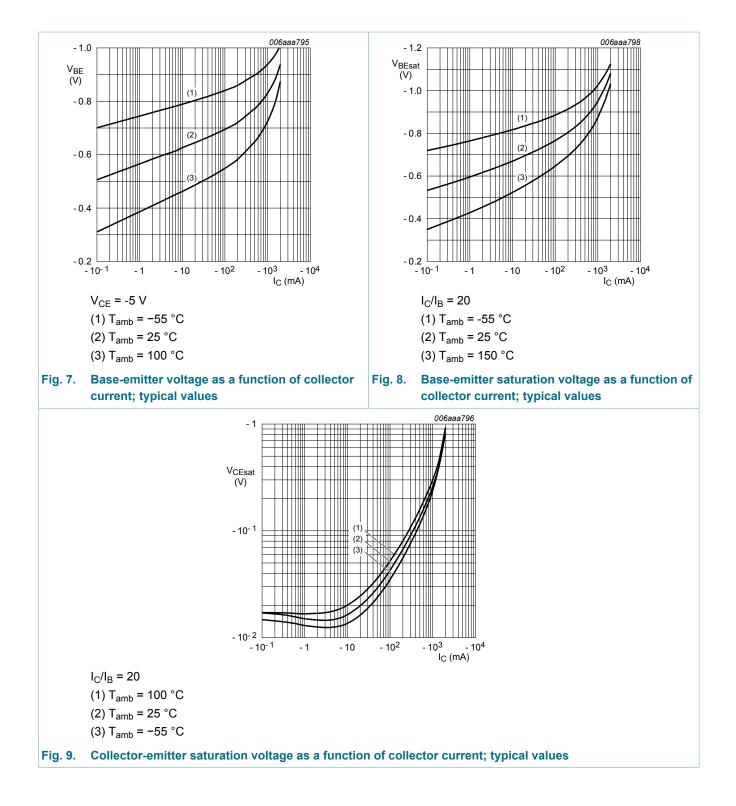
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_{C}$ = -1 A; $I_{B}$ = -100 mA; pulsed; $t_{p}$ ≤ 300 μs; δ ≤ 0.02 ; $T_{amb}$ = 25 °C	-	-	-1.2	V
V <sub>BEon</sub>	base-emitter turn-on voltage	$V_{CE}$ = -5 V; I <sub>C</sub> = -1 A; pulsed; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02 ; T <sub>amb</sub> = 25 °C	-	-	-1.1	V
f <sub>T</sub>	transition frequency	$V_{CE}$ = -10 V; I <sub>C</sub> = -50 mA; f = 100 MHz; T <sub>amb</sub> = 25 °C	150	-	-	MHz
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = -10 V; I <sub>E</sub> = 0 A; i <sub>e</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C	-	-	12	pF







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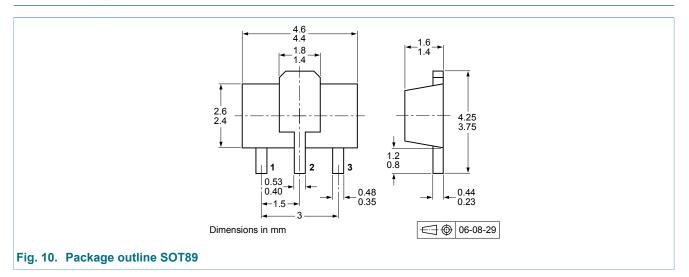


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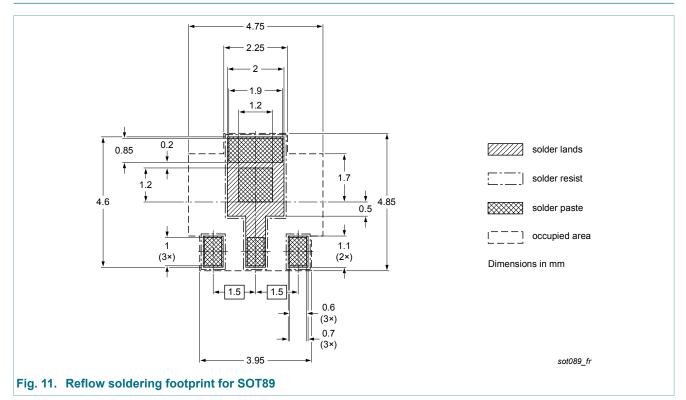
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### 8. Package outline



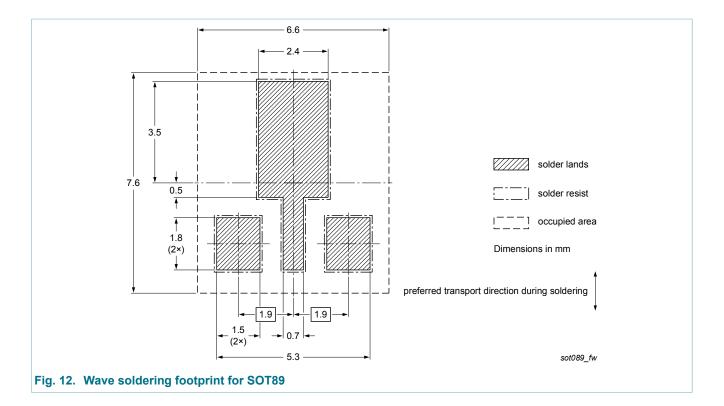
### 9. Soldering



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### 10. Revision history

Table 8.	<b>Revision his</b>	story	

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBSS5240X v.1	20121019	Product data sheet	-	-

#### 40 V, 2 A PNP low VCEsat (BISS) transistor

### 11. Legal information

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Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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